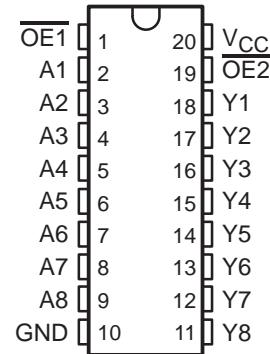


# CD74FCT541 BiCMOS OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCBS741 – JULY 2000

- BiCMOS Technology With Low Quiescent Power
- Buffered Inputs
- Noninverted Outputs
- Input/Output Isolation From  $V_{CC}$
- Controlled Output Edge Rates
- 64-mA Output Sink Current
- Output Voltage Swing Limited to 3.7 V
- SCR Latch-Up-Resistant BiCMOS Process and Circuit Design
- Package Options Include Plastic Small-Outline (M) and Shrink Small-Outline (SM) Packages and Standard Plastic (E) DIP

E, M, OR SM PACKAGE  
(TOP VIEW)



## description

The CD74FCT541 is an octal buffer/driver with 3-state outputs that is ideal for driving bus lines or buffer memory address registers and uses a small-geometry BiCMOS technology. The output stage is a combination of bipolar and CMOS transistors that limits the output high level to two diode drops below  $V_{CC}$ . This resultant lowering of output swing (0 V to 3.7 V) reduces power-bus ringing [a source of electromagnetic interference (EMI)] and minimizes  $V_{CC}$  bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 64 mA.

The 3-state control gate is a two-input AND gate with active-low inputs, so that if either output-enable ( $\overline{OE1}$  or  $\overline{OE2}$ ) input is high, all corresponding outputs are in the high-impedance state. The outputs provide noninverted data when they are not in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The CD74FCT541 is characterized for operation from 0°C to 70°C.

**FUNCTION TABLE**  
(each buffer/driver)

INPUTS			OUTPUT Y
$\overline{OE1}$	$\overline{OE2}$	A	
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z



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**TEXAS  
INSTRUMENTS**

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**recommended operating conditions (see Note 3)**

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.75	5.25	V
V <sub>IH</sub>	High-level input voltage	2		V
V <sub>IL</sub>	Low-level input voltage		0.8	V
V <sub>I</sub>	Input voltage	0	V <sub>CC</sub>	V
V <sub>O</sub>	Output voltage	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current		-15	mA
I <sub>OL</sub>	Low-level output current		64	mA
Δt/Δv	Input transition rise or fall rate	0	10	ns/V
T <sub>A</sub>	Operating free-air temperature	0	70	°C

NOTE 2: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	T <sub>A</sub> = 25°C		MIN	MAX	UNIT
			MIN	MAX			
V <sub>IK</sub>	I <sub>I</sub> = -18 mA	4.75 V		-1.2		-1.2	V
V <sub>OH</sub>	I <sub>OH</sub> = -15 mA	4.75 V	2.4		2.4		V
V <sub>OL</sub>	I <sub>OL</sub> = 64 mA	4.75 V		0.55		0.55	V
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5.25 V		±0.1		±1	μA
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.25 V		±0.5		±10	μA
I <sub>OS</sub> <sup>†</sup>	V <sub>I</sub> = V <sub>CC</sub> or GND, V <sub>O</sub> = 0	5.25 V		-60		-60	mA
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	5.25 V		8		80	μA
ΔI <sub>CC</sub> <sup>‡</sup>	One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND	5.25 V		1.6		1.6	mA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND			10		10	pF
C <sub>o</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND			15		15	pF

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 100 ms.

<sup>‡</sup> This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V<sub>CC</sub>.

**switching characteristics over recommended operating conditions, V<sub>CC</sub> = 5 V ± 0.25 V (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T <sub>A</sub> = 25°C	MIN	MAX	UNIT
			TYP			
t <sub>pd</sub>	A	Y	6	2	8	ns
t <sub>en</sub>	$\overline{OE}$	Y	7.5	2	10	ns
t <sub>dis</sub>	$\overline{OE}$	Y	7.1	2	9.5	ns

**noise characteristics, V<sub>CC</sub> = 5 V, C<sub>L</sub> = 50 pF, T<sub>A</sub> = 25°C**

PARAMETER	MIN	TYP	MAX	UNIT
V <sub>OL(P)</sub> Quiet output, maximum dynamic V <sub>OL</sub>		1		V
V <sub>OH(V)</sub> Quiet output, minimum dynamic V <sub>OH</sub>		0.5		V
V <sub>IH(D)</sub> High-level dynamic input voltage	2			V
V <sub>IL(D)</sub> Low-level dynamic input voltage			0.8	V

**CD74FCT541**  
**BiCMOS OCTAL BUFFER/DRIVER**  
**WITH 3-STATE OUTPUTS**

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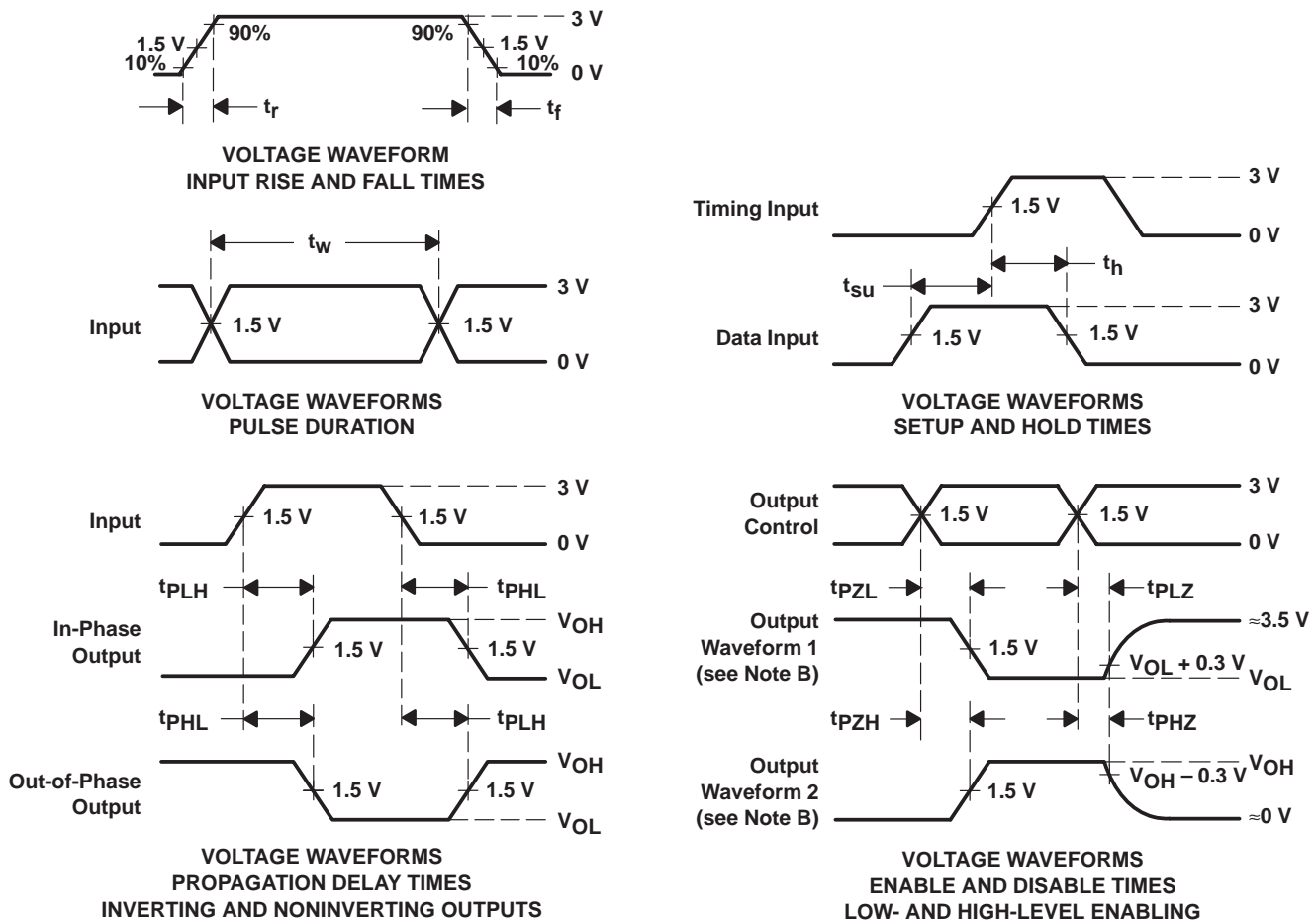
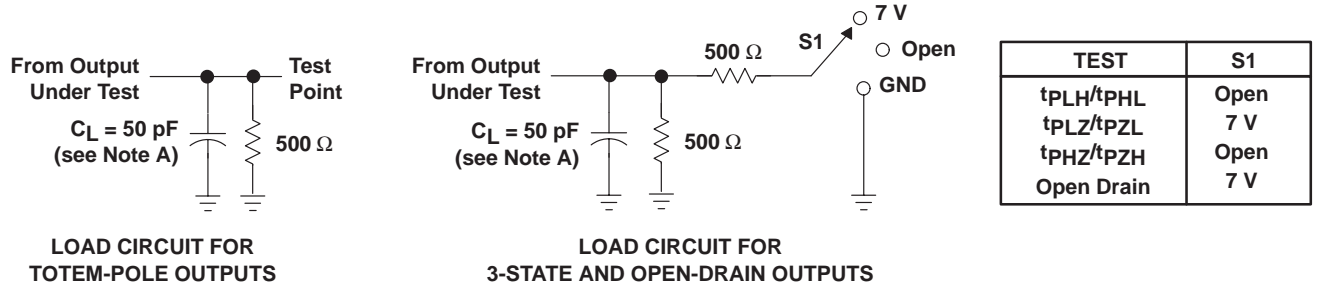
**operating characteristics,  $T_A = 25^\circ\text{C}$**

PARAMETER		TEST CONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	No load, $f = 1\text{ MHz}$	40	pF



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PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.  
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.  
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> and t<sub>f</sub> = 2.5 ns.  
 D. The outputs are measured one at a time with one input transition per measurement.  
 E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.  
 F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.  
 G. t<sub>PHL</sub> and t<sub>PLH</sub> are the same as t<sub>pd</sub>.

Figure 1. Load Circuit and Voltage Waveforms

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">CD74FCT541E</a>	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	CD74FCT541E
<a href="#">CD74FCT541M</a>	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT541M

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

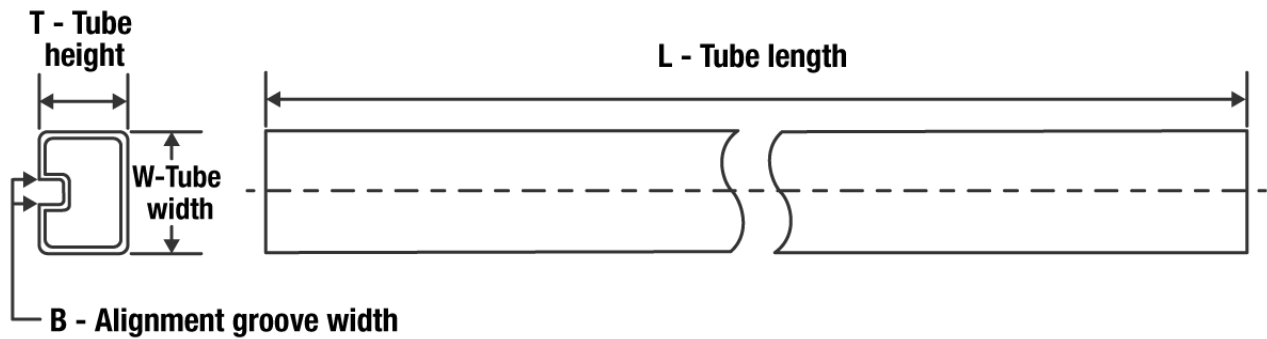
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
CD74FCT541E	N	PDIP	20	20	506	13.97	11230	4.32
CD74FCT541M	DW	SOIC	20	25	507	12.83	5080	6.6

N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\triangle C$  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - $\triangle D$  The 20 pin end lead shoulder width is a vendor option, either half or full width.

4040049/E 12/2002



# DW0020A



# PACKAGE OUTLINE

## SOIC - 2.65 mm max height

SOIC



4220724/A 05/2016

**NOTES:**

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

# EXAMPLE BOARD LAYOUT

DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE  
SCALE:6X



SOLDER MASK DETAILS

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NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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